

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3679	((heat\$3 or hot) near15 plate\$1) near15 ceramic)	USPAT	OR	OFF	2004/12/05 16:43
L2	1577	1 and (substrate\$1 or wafer\$1)	USPAT	OR	OFF	2004/12/05 15:03
L3	754	2 and ((resistance or resistive) near10 heat\$3)	USPAT	OR	OFF	2004/12/05 15:04
L4	6	3 and (((resistive or resistance) near10 heat\$3) near15 ((individual\$2 or separate\$2 or independent\$2) near10 (controll\$3 or energiz\$3)))	USPAT	OR	OFF	2004/12/05 15:12
L5	7	3 and (((resistive or resistance) near10 heat\$3) near15 ((two or multiple) near8 circuit\$3))	USPAT	OR	OFF	2004/12/05 15:11
L6	262	3 and ((measur\$3 or determin\$3) near10 temperature\$1)	USPAT	OR	OFF	2004/12/05 17:11
L7	94	6 and (control\$3 near8 (power or unit))	USPAT	OR	OFF	2004/12/05 15:14
L8	14	7 and (memory near10 (unit\$1 or device\$1))	USPAT	OR	OFF	2004/12/05 15:15
L9	6	8 and (operation near8 (unit\$1 or device\$1))	USPAT	OR	OFF	2004/12/05 15:16
L10	2811	((heat\$3 or hot) near8 plate\$1) near8 ceramic)	USPAT	OR	OFF	2004/12/05 16:44
L11	93	(((heat\$3 or hot) near8 plate\$1) near8 ceramic) near8 (((resistive or resistance) near8 heat\$3) near8 (element\$1 or device\$1)))	USPAT	OR	OFF	2004/12/05 16:46
L12	40	11 and (substrate\$1 or wafer\$1)	USPAT	OR	OFF	2004/12/05 16:46
L13	18	6 and (((calculat\$3 or determin\$3) near10 (power\$3 or energ\$5)) near10 temperature)	USPAT	OR	OFF	2004/12/05 17:25
L14	2	6 and (((((calculat\$3 or determin\$3) near10 (power\$3 or energ\$5)) near10 (resistive or resistance)) near10 temperature)	USPAT	OR	OFF	2004/12/05 17:29
L15	2	3 and (((((calculat\$3 or determin\$3) near10 (power\$3 or energ\$5)) near10 (resistive or resistance)) near10 temperature)	USPAT	OR	OFF	2004/12/05 17:30
L16	15	6 and (((((calculat\$3 or determin\$3) same (power\$3 or energ\$5)) same (resistive or resistance)) same temperature)	USPAT	OR	OFF	2004/12/05 17:38
L17	13	16 not 14	USPAT	OR	OFF	2004/12/05 17:30

L18	18	3 and (((calculat\$3 or determin\$3) same (power\$3 or energ\$5)) same (resistive or resistance)) same temperature)	USPAT	OR	OFF	2004/12/05 17:54
L19	16	18 not 15	USPAT	OR	OFF	2004/12/05 17:40
L20	3	18 not 16	USPAT	OR	OFF	2004/12/05 17:40
L21	54	1 and (((calculat\$3 or determin\$3) same (power\$3 or energ\$5)) same (resistive or resistance)) same temperature)	USPAT	OR	OFF	2004/12/05 17:54
L22	36	21 not 18	USPAT	OR	OFF	2004/12/05 17:55
L23	39	21 not 16	USPAT	OR	OFF	2004/12/05 17:55
L24	36	22 not 16	USPAT	OR	OFF	2004/12/05 17:57
L25	6	24 and (substrate\$1 or wafer\$1)	USPAT	OR	OFF	2004/12/05 17:58